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Table of Contents

Foreword	ix
Committees	xi
Tutorials	xv
Keynote Speakers	xix
Papers	
Session A – Low Power	
A1 – A Back Biasing Voltage Generator for 28-nm UTBB-FDSOI RVT CMOS Digital Circuits <i>M. Pelicia¹, R. Coimbra¹, P. Zanetta²</i> ¹ NXP Semiconductors, Brazil, ² Uberaba, Brazil	1
A2 – Evaluation of Compensation Techniques for CMOS Operational Amplifier Design <i>M. Zaidi¹, I. Grout¹, A. A'Ain²</i> ¹ University of Limerick, Ireland, ² UTM, Malaysia	5
A3 – Low Power GDI ALU Design with Mixed Logic Adder Functionality <i>J. Rahal¹, B. Maamari², B. Hajri², R. Kanj², M. Mansour², A. Chehab²</i> ¹ University of Texas at Austin, United States, ² American University of Beirut, Lebanon	9
A4 – Design of a 3T Current Reference for Low-Voltage, Low-Power Operation <i>R. De Rose¹, F. Crupi¹, M. Paliy², M. Lanuzza¹, G. Iannaccone²</i> ¹ University of Calabria, Italy, ² University of Pisa, Italy	13
A5 – 3D Printed Wearable Sensor Tag based on UHF RFID ICs Implementing a Novel Interrogation Modality <i>R. Colella, L. Catarinucci</i> University of Salento, Italy	17
A6 (Invited) – Approximate Computing in the Nanoscale Era <i>A. Strollo, D. Esposito</i> University of Napoli Federico II, Italy	21
Session B – SoC/MPSoC/SIP	
B1 – A Novel Priority-Driven Arbiter for the Router in Reconfigurable Network-on-Chips <i>H. Nguyen, X. Tran</i> Vietnam National University, Vietnam	25
B2 – Delay Estimation, Chip-Power Analyses and Comparison of Single-Level and Multi-Level Recursive Vedic Algorithm with Conventional Algorithms for Digital Multiplier <i>A. Naik, D. Pal</i> BITS Pilani K. K. Birla, India	29

B3 – Real-Time Digital Implementation of a Principal Component Analysis Algorithm for Neurons Spike Detection

E. Vallicelli¹, F. Fary¹, M. Reato², M. Maschietto², F. Rocchi², S. Vassanelli², D. Guarrera², G. Collazuol², R. Zeitler³, A. Baschiroto¹, M. De Matteis¹

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33

Session C – Analog Techniques

C1 (Invited) – Three-Stage Single-Miller CMOS OTA Driving 10 nF with 1.46-MHz GBW

A. Grasso¹, S. Pennisi¹, G. Palumbo¹, D. Marano²

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37

C2 – A Programmable Dynamic Range and Digital Output Rate Oscillator-Based Readout Interface for MEMS Resistive and Capacitive Sensors

F. Ciciotti¹, C. Buffa², R. Gagg², A. Baschiroto¹

¹University of Milano-Bicocca, Italy, ²Infineon Technologies, Austria

41

C3 – Low-Power Reference Buffer for Successive Approximation Register Analog-to-Digital Converters

S. D'Amico, S. Marinaci

University of Salento, Italy

45

C4 – Fully Analog Automatic Stray Compensation for Bridge-Based Differential Capacitive Sensor Interfaces

G. Barile¹, G. Ferri¹, V. Stornelli¹, F. Parente¹, E. Sisinni², A. Depari², A. Flammini²

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49

C5 – A Low-Offset Low-Kickback-Noise Dynamic Comparator

H. Molaei, K. Hajsadeghi

Sharif University of Technology, Iran

N/A

C6 – About Figure-of-Merit for Continuous-Time Analog Filters

F. Fary, E. Vallicelli, M. De Matteis, A. Baschiroto

University of Milano-Bicocca, Italy

57

C7 – A High-Speed Time Amplifier with the Re-Configurable Gain

H. Molaei, K. Hajsadeghi

Sharif University of Technology, Iran

N/A

Session D – RF Techniques

D1 – State Space Model-Oriented Design for Efficiency Improvement of Class-E Power Amplifier

D. De Venuto, G. Mezzina

Politecnico di Bari, Italy

65

D2 – Active Filters Tuning Interface

L. Pantoli¹, A. Leoni¹, V. Stornelli¹, G. Leuzzi¹, Z. Marinkovic²

¹University of L'Aquila, Italy, ²University of Nis, Serbia

69

D3 – A 76-81 GHz CMOS Down-Conversion Mixer for Automotive Radar

D. Pan¹, Z. Duan², L. Huang¹, Y. Wang², Y. Zhou², B. Wu², L. Sun¹

¹University of Science and Technology of China, China, ²East China Research Institute of Electronic Engineering, China

73

D4 – Low Noise Active Loop Filter for Radar PLL Applications

A. Donno¹, S. D'Amico², R. Nonis³, P. Thurner³

¹Thetis Microelectronics, Italy, ²University of Salento, Italy, ³Infineon Technologies, Austria

77

D5 – Common Emitter and Cascode Topologies at G band: A Comparative Study on a Single Stage 183-GHz Power Amplifier	
<i>A. Ali, E. Cipriani, P. Colantonio</i>	
University of Roma Tor Vergata, Italy	81
D6 (Invited) – Solid-State Power Amplifiers for Satellite Communication: A Feasible Solution	
<i>P. Colantonio, E. Cipriani, R. Giofrè, F. Giannini</i>	
University of Roma Tor Vergata, Italy	85
D7 (Invited) – Low Phase Noise K-band VCO and High Efficiency E-band Power Amplifier for Mobile Network Backhaul in SiGe BiCMOS	
<i>A. Mazzanti, E. Rahimi, N. Lacaita, Z. Junlei, M. Bassi, F. Svelto</i>	
University of Pavia, Italy	89
Session E – CAD/DFM/DFT/DFR/DFY	
E1 – DRC Code Coverage Test: A Novel QA Methodology	
<i>Y. Lee¹, J. Park¹, M. Elsayed², M. Gadallah², M. Alimam²</i>	
¹ Samsung Electronics, South Korea, ² Mentor, Egypt	93
E2 (Invited) – Test Generation for Microfluidic Fully-Programmable Valve Arrays (FPVAs) with Heuristic Acceleration	
<i>C. Liu¹, B. Li¹, B. Bhattacharya², K. Chakrabarty³, T. Ho⁴, U. Schlichtmann¹</i>	
¹ Technical University of Munich, Germany, ² Indian Statistical Institute, India, ³ Duke University, United States, ⁴ National Tsing Hua University, Taiwan	97
E3 – Wire Congestion Aware High-Level Synthesis Flow with Source Code Compiler	
<i>M. Tatsuoka, M. Kaneko</i>	
Japan Advanced Institute of Science and Technology, Japan	101
E4 (Invited) – Design of AlGaIn Microring Resonators for Broadband Biphoton Excitation	
<i>V. Passaro¹, F. De Leonardi¹, R. Soref²</i>	
¹ Politecnico di Bari, Italy, ² University of Massachusetts at Boston, United States	105
Session F – Advanced Memory Devices	
F1 – Memristor Models Optimization for Large-Scale 1T1R Memory Arrays	
<i>B. Hajri¹, H. Aziza², M. Mansour¹, A. Chehab¹</i>	
¹ American University of Beirut, France, ² University of Aix-Marseille, France	109
F2 (Invited) – OTS Selector Devices: Material Engineering for Switching Performance	
<i>M. Cyrille, A. Verdy, G. Navarro, G. Bourgeois, J. Garrione, M. Bernard, S. Chiara, E. Nowak</i>	
CEA-LETI, France	113
F3 – An Area Efficient Low-Voltage 6-T SRAM Cell Using Stacked Silicon Nanowires	
<i>Y. Huang¹, M. Chiang¹, S. Gupta², S. Wang¹</i>	
¹ National Cheng Kung University, Taiwan, ² Purdue University, United States	117
F4 (Invited) – Embedding Hafnium Oxide Based FeFETs in the Memory Landscape	
<i>S. Slesazeck, U. Schroeder, T. Mikolajick</i>	
NaMLab, Germany	121
F5 (Invited) – Spin Transfer Torque Magnetic Random-Access Memory: Towards Sub-10-nm Devices	
<i>N. Perrissin, S. Lequeux, N. Strelkov, L. Vila, L. Prejbeanu-Buda, S. Auffret, R. Sousa, L. Prejbeanu, B. Dieny</i>	
Spintec, France	125
Session G – 3D & Advanced Transistors/Material	

G1 – Application Fields Overview of Carbon Nanotubes in Electronics and Propulsion: CNTs Photo-Ignition by White Power LEDs for Improved Fuel Combustion <i>R. De Fazio, P. Primiceri, A. Carlucci, P. Visconti</i> University of Salento, Italy	129
G2 (Invited) – High Voltage IC Technology: Continuously Evolving Challenges <i>M. Griswold, A. Khorasani</i> ON Semiconductor, United States	133
G3 – Fast Multi-Parametric Method for Mechanical Properties Estimation of Clamped-Clamped Perforated Membranes <i>L. Francioso¹, C. De Pascali¹, P. Siciliano¹, A. Bagolini², D. Duraccio³</i> ¹ CNR-IMM, Italy, ² Fondazione Bruno Kessler, Italy, ³ CNR-IMAMOTER, Italy	137
G4 (Invited) – A Review on Opportunities Brought by 3D-Monolithic Integration for CMOS Device and Digital Circuit <i>F. Andrieu, P. Batude, L. Brunet, C. Fenouillet-Béranger, D. Lattard, S. Thuries, O. Billoint, R. Fournel, M. Vinet</i> CEA-LETI, France	141
G5 (Invited) – Sequential 3D: Key Integration Challenges and Opportunities for Advanced Semiconductor Scaling <i>A. Vandooren, L. Witters, J. Franco, A. Mallik, B. Parvais, Z. Wu, A. Walke, V. Deshpande, E. Rosseel, A. Hikavyy, W. Li, L. Peng, N. Rassoul, G. Jamieson, F. Inoue, G. Verbinen, K. Devriendt, L. Teugels, N. Heylen, E. Vecchio, Z. Tao, N. Waldron, V. de Heyn, D. Mocuta, N. Collaert</i> imec, Belgium	145
G6 – 55 to 59 GHz MMIC Non-Foster Circuit Enabled Class-J GaAs pHEMT Power Amplifier <i>C. Akwuruoha, Z. Hu</i> University of Manchester, United Kingdom	149
G7 (Invited) – Ge CMOS Technology with Advanced Interface and Junction Engineering <i>Y. Zhao, Z. Zheng, J. Li, D. Ni, R. Zhang</i> Zhejiang University, China	153
Session H – Reliability and ESD Protection	
H1 – Optimized in Situ Heating Control on a New MOS Device Structure in 28-nm UTBB FD-SOI CMOS Technology <i>P. Galy¹, R. Lethiecq¹, M. Bawedin²</i> ¹ STMicroelectronics, France, ² IMEP-LAHC, France	157
H2 (Invited) – Spectral Variation Analysis of Integrated Silicon Photonics Devices by Using Optical Wafer Probing <i>T. Horikawa^{1, 2}, T. Mogami²</i> ¹ AIST, Japan, ² PETRA, Japan	161
H3 – Non-Tunneling Origin of the 1/f Noise in SiC MOSFET <i>K. Cheung, J. Campbell</i> NIST, United States	165
H4 – Soft Failures in Integrated Circuits as a Matter of ESD Events <i>T. Ostermann</i> JKU University of Linz, Austria	169
H5 (Invited) – Electrical Characterization of Process Induced Effects on Non-Silicon Devices <i>C. Young, P. Bolshakov, R. Rodriguez-Davila, P. Zhao, A. Khosravi, I. Mejia, M. Quevedo-Lopez, C. Hinkle, R. Wallace</i> University of Texas at Dallas, United States	173

Session I – Emerging Technologies**I1 – A Smart Device for Supporting Mechanical Ventilatory-Therapy**

A. Radogna¹, S. Capone¹, G. Di Lauro², N. Fiore², L. Francioso¹, F. Casino¹, P. Siciliano¹, S. Sabina³, E. Sabato⁴

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I2 (Invited) – Lab-on-Chip for Life Science: from Medical Diagnostics to Food Quality Control

E. Primiceri¹, M. Chiriaco¹, G. Maruccio²

¹CNR-NANOTEC, Italy, ²University of Salento, Italy 181

I3 – Design of an Arduino-Based Platform Interfaced by Bluetooth Low Energy with Myo Armband for Controlling an Under-Actuated Transradial Prosthesis

F. Gaetani¹, G. Zappatore¹, P. Visconti², P. Primiceri²

¹BionIT Labs, Italy, ²University of Salento, Italy 185

I4 (Invited) – High-k YCTO Thin Films for Electronics

A. Monteduro¹, Z. Ameer¹, S. Rizzato¹, A. Leo¹, M. Martino¹, A. Caricato¹, V. Tasco², I. Lekshmi³, A. Hazarika⁴, D. Choudhury⁴, E. Mazzotta¹, C. Malitesta¹, D. Sarma⁴, G. Maruccio¹

¹University of Salento, Italy, ²CNR-NANOTEC, Italy, ³CMR Institute of Technology, Italy, ⁴Indian Institute of Science, India 189

I5 – Event-Driven Cooperative-Based Internet-of-Things (IoT) System

M. Rescati¹, M. De Matteis¹, D. Pau², R. Schettini¹, M. Paganoni¹, A. Baschirotto¹

¹University of Milano-Bicocca, Italy, ²STMicroelectronics, Italy 193

I6 (Invited) – Time-Resolved Single-Photon Detectors: Integration Challenges in CMOS Technologies

M. Perenzoni, M. Moreno-Garcia, L. Gasparini, N. Massari

Fondazione Bruno Kessler, Italy 197

Author Index

201